



PICOPOWER™-RG1-1064-10K

Diode-Pumped High Energy Picosecond Laser 1064 nm, 100 µJ, 20 ps, 10 kH PICOPOWER[®] - RG1-1064-10K



he **PICOPOWER™- RG1-1064-10K** picosecond laser delivers ultrashort pulses with high energy, high peak and average power at 1064 nm wavelength with variable repetition rates from single shot to 10 kHz. It features a unique synchronization capability with unsurpassed 3.5 ps jitter for pulses on demand. Optional wavelengths at 532 nm, 355 nm and 266 nm are available collinearly or as multiple output beams. The distinctive features of this laser are excellent power, pulse-to-pulse and beam pointing stability, diffraction-limited output beam, pulse-on-demand triggering and peak power of more than 2 MW with less than 30 W electrical power consumption. It is an ideal choice for numerous applications, including micro-machining of metal and nonmetal materials, semiconductor wafer inspection, carving, nonlinear optics, ultrafast spectroscopy and many others.

Features

- Single or multiple outputs at 1064 nm, 532 nm, 355 nm or 266 nm wavelengths
- Unsurpassed 3.5 ps rms jitter to external trigger
- Less than **30 ps** pulse width
- **50 µJ** pulse energy at 1064 nm
- More than **2 MW** peak power at 1064 nm
- Internal and external trigger
- Air-cooled, compact and cost effective
- Excellent Gaussian TEM beam profile
- Variable repetition rate

Applications

- High-speed and precision micro-machining (glass, silicon, plastics, etc.)
- Fluorescence lifetime measurements
- Multi-photon non-linear microscopy
- Marking, carving and 3D engraving
- Time-resolved spectroscopy
- Terahertz imaging
- Nonlinear optics



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High-Energy Picosecond Laser: PICOPOWER™-RG1-1064-10K

Technical Specifications:	Тур
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Parameter	U
Wavelength	r
Pulse Energy, single shot to 5 kHz	
Pulse Energy @ 10 kHz	
Pulse Width, single shot to 10 kHz	

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Parameter	Unit	Fundamental	Harmonics (optional)			
Wavelength	nm	1064	532	355	266	
Pulse Energy, single shot to 5 kHz	μJ	55	33	16	12	
Pulse Energy @ 10 kHz	μJ	50	29	13.5	10	
Pulse Width, single shot to 10 kHz	ps	< 30	< 30	< 25	< 25	
Peak Power, single shot to 5 kHz	MW	2.3	1.7	0.9	0.7	
Peak Power @ 10 kHz	MW	2.1	1.4	0.8	0.6	
Average Power @ 10 kHz	mW	500	290	135	100	
Long Term Power Stability (8 hrs)	%, rms	< 1.0	< 2.0	< 3.0	< 4.0	
Pulse-to-Pulse Energy Stability	%, rms	< 1.0	< 2.0	< 3.0	< 4.0	
Beam Diameter, 1/e ²	mm	1.4 Available on request				
Polarization (linear)	%	> 99.5	> 99.9	> 99.9	> 99.9	
Beam Divergence	mrad	< 1.2	< 2.0	< 3.0	< 3.0	
Beam Pointing Stability (rms)	µrad	< 30	< 30	< 30	< 30	
Pre-Pulse Contrast Ratio ¹⁾		> 10 ³ :1	> 10 ⁵ : 1	> 10 ⁷ : 1	> 10 ⁹ : 1	
Post-Pulse Contrast Ratio ¹⁾		> 10 ² : 1	> 10 ³ : 1	> 105: 1	> 10 ⁷ : 1	
Spatial Mode / M ²		$TEM_{00} / M^2 < 1.2$ $TEM_{00} / M^2 < 1.5$				
Repetition Rate	kHz	Single shot to 10 kHz				
Internal Trigger Repetition Rate	kHz	0.1 10				
External Trigger Repetition Rate	kHz	Single shot to 10 kHz				
External Trigger Specifications		TTL (4.5 5.5 V on 50 Ω load) Rising edge: < 10 ns; Pulse width: min. 250 ns, max. 1.3 μs				
Delay of Laser Pulse to TRIG IN	ns	~ 500				
Optical SYNC OUT Pulse	ps	Optional, jitter < 1 ps, rise time < 50 ps				
Electrical SYNC OUT Pulse		+5 V on 50 Ω load				
Jitter of Laser Pulse to External Trigger	ps, rms	3.5				
Delay SYNC OUT to Laser Pulse	ns	Adjustable from -100 to +1000				
Jitter of Electrical SYNC OUT Pulse	ps	50				
MECHANICAL CHARACTERISTICS						

	Dimensions	Weight		
Laser Head	165 x 95 x 700 mm ³	10 kg		
Laser Diode Driver	130 x 65 x 105 mm ³ 1 kg			
Control Unit	105 x 65 x 105 mm ³	1 kg		
GENERAL CHARACTERISTICS				
Power Requirements	+12 V DC, 5 A or 100 240 VAC with AC/DC adapter			
Power Consumption	< 30 W			
Operating Temperature Range	15°C – 35°C			
Cooling	Passive (convection)			
Typical warm-up time	< 15 min			
Beam height	Min. 93 mm, max. 103 mm, adjustable			

Note: ¹⁾ Peak-to-peak with respect to residual pulses.

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High-Energy Picosecond Laser: PICOPOWER™-RG1-1064-10K

Performance of PICOPOWER[™]-RG1-1064-10K: Typical Values



Pulse width and peak power at different repetition rates for 1064 nm wavelength.



Peak power at 1064 nm and its harmonic wavelengths at 10 kHz repetition rate.



Pulse width at 1064 nm wavelength before deconvolution measured with 30 GHz photodetector.



Pulse energy at different repetition rates for 1064, 532, 355 and 266 nm wavelengths.



Average power at different repetition rates for 1064, 532, 355 and 266 nm wavelengths.



Spectral bandwidth at 1064 nm wavelength.

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High-Energy Picosecond Laser: PICOPOWER™-RG1-1064-10K

Performance of PICOPOWER™-RG1-1064-10K: Typical Values



Long-term power stability at 1064 nm wavelength.



Beam pointing stability at 10 kHz repetition rate.



3D and 2D far-field beam profile measured at 540 mm distance from laser head for 1064 nm wavelength.



1D cross section and Gaussian fit showing nearly 95% overlap.



Beam quality measured at maximum output power according to ISO 11146 standard (\pm 5%).

 $M_{eff}^2 = 1.02$ Div_{eff} = 0.93 mrad BPP_{eff} = 0.34 mrad*mm z0_{eff} = 1551 mm

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